substrate for supplying a signal to one of said X-direction signal line and said Y-direction signal line.

Please add new claims 11-14 as follows:

--11. The display device according to claim 10 wherein said thin film transistor and said another thin film transistor are manufactured simultaneously.

12. The display device according to claim 1 wherein said barrier metal layer comprises titanium nitride where a concentration of nitrogen is 50 atm% or less.

13. The display device according to claim 6 wherein said conductive layer comprises titanium nitride where a concentration of nitrogen is 50 atm% or less.

14. The display device according to claim 9 wherein said conductive layer comprises titanium nitride where a concentration of nitrogen is 50 atm% or less.--

REMARKS

Claim 1-3 and 6-14 are pending. By this amendment, claims 4 and 5 are canceled, claim 10 is amended and claims 11-14 are added. Reconsideration in view of the above amendments and the following remarks is respectfully requested.

The Office Action rejects claim 10 under 35 U.S.C. § 102(e) as anticipated by U.S. Patent No. 5,550,066 to Tang et al. (hereinafter "Tang"). This rejection is respectfully traversed.

The Office Action asserts that Tang discloses an organic electroluminescence display device and a substrate having an insulating surface, a thin film transistor formed over the substrate having an active layer comprising silicon including source, drain and channel regions, a transparent electrode, an organic electroluminescence layer adjacent to the transparent electrode and a peripheral driving circuit comprising another thin film transistor.

In contrast, claim 10 recites, inter alia, "An organic electroluminescence display device comprising... at least one X-direction signal line over said substrate; at least one Y-direction signal line crossing said X-direction signal line; a thin film transistor formed over said substrate at an intersection of said X-direction signal line and said Y-direction signal line... and a peripheral